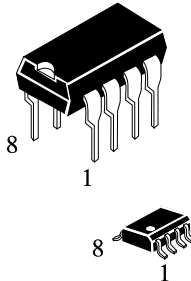# Fixed Frequency Current Mode PWM Controller

DESCRIPTION

Fixed frequency current-mode PWM controller. It is specially designed for Off Line And DC-to-DC converter applications with minimal external component. This integrated circuit features a trimmed oscillator for precise duty cycle control. a temperature compensated reference, high gain arror amplifier, current sensing comparator, and a high current totempole output ideally suited for driving a power MOSFET.

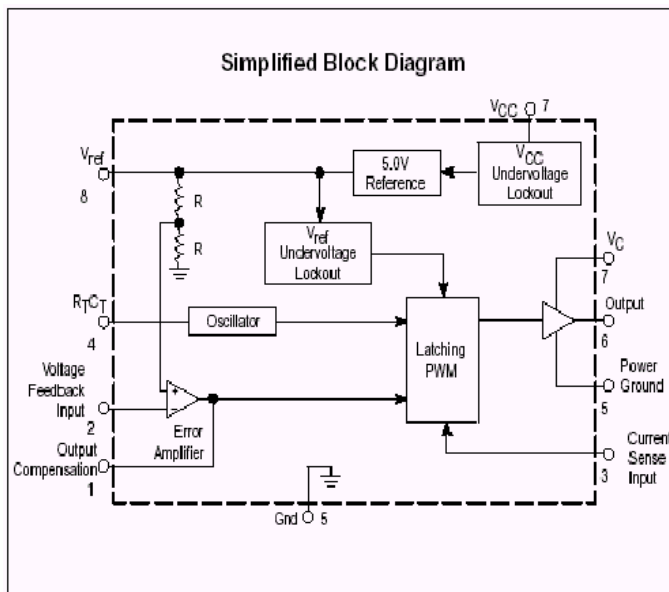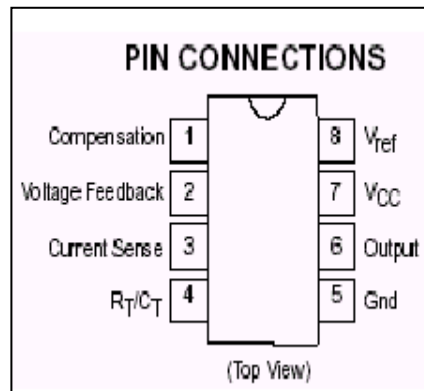Protection circuitry includes built in under-voltage lockout and current limiting.

FEATURES

♦ Automatic Feed Forward Compensation

♦ High Gain Totem Pole Output

♦ Internally Trimmed Bandgap Reference

♦ Undervoltage Lockout with Hysteresis

♦ Low Start Up Current

♦ Optimized for offline converter

♦ Double pulse suppression

♦ Current mode operation to 500KHz

N SUFFIX
PLASTIC

8
1

D SUFFIX
SOIC

8
1

ORDERING INFORMATION

IL3843N Plastic
IL3843D SOIC
T_A = 0° to 70° C for all packages.

PIN CONNECTIONS

Compensation	1		8	V_{ref}
Voltage Feedback	2		7	V_{CC}
Current Sense	3		6	Output
R_T/C_T	4		5	Gnd

(Top View)

ORDERING INFORMATION

Device	Operating Temperature Range	Package
IL3843N	T_A=0° to +70°C	DIP-8
IL3843D	T_A=0° to +70°C	SOP-8

Simplified Block Diagram

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PIN FUNCTION DESCRIPTION

Pin No.	Function	Description
1	Compensation	This pln is the Error Amplifier output and is made available for loop compensation
2	Voltage Feedback	This is the inverting input of the Error Amplifier. It is normally connected to the switching power supply outpul through a resistor divider.
3	Current Sense	A voltage proportional to inductor current is connected to this input. The PWM uses this. information to terminate the output switch conduction
4	RT/CT	The Oscillator frequency and maximum Output duty cycle are programmed by connecting resistor R_T to V_{REF} and capacitor C_T to ground. Operation to 500kHz is possible.
5	GND	This pin is the combined conlrol circuitry and power ground
6	Output	This output directly drives the gate of a power MOSFET. Peak currents up to 1,0A are sourced and sunk by this pin.
7	Vcc	This pin is the positive supply of the control IC.
8	V_{REF}	This is the reference output. It provides chsarging current for capacitor C_T through resistor R_T

ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Total Power Supply and Zener Current	$(I_{CC}+ I_Z)$	30	mA
Output Current	I_O	±1.0	A
Output Energy (Capacitive Load per Cycle)	W	5.0	μJ
Error Amp Output Sink Current	I_{OE}	10	mA
Current Sense and Voltage Feedback Inputs	Vin	-0.3 to 5.5	V
Maximum Power Dissipation @ T_A= 25°C: DIP-8 SOP-8	P_D	0.862 0.625	W
Thermal Resistance,Junction-to-Air	$R_{\theta JA}$	145	°C/W
Operating Junction Temperature	T_J	+150	°C
Storage Temperature Range	T_{stg}	-65 ~ +150	°C

* Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.
Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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ELECTRICAL CHARACTERISTICS (Vcc=15V unless otherwise noted)

| Characteristics	Symbol	Min	Max	Unit
REFERENCE SECTION				
Reference Output Voltage (I_O=1.0mA, V_{CC}=15V**,**T_A=25±10°C) (I_O=1.0mA, V_{CC}=15V**,**T_A= Tlow to Thigh)	V_{ref}	4.9 4.865	5.1 5.135	V
Line Regulation (V_{CC}=12V to 25V,T_A=Tlow to Thigh)	Reg_{line}		20	mV
Load Regulation (I_O=1.0 to 20mA,T_A=Tlow to Thigh)	Reg_{load}		25	mV
Total Output Variation over Line,Load,Temperature (Note1) (V_{CC}=12V, I_O=1.0mA,T_A=Tlow to Thigh) (V_{CC}=25V, I_O=20mA,T_A=Tlow to Thigh)	Vfinal	4.82	5.18	V
Output Short Circuit Current (V_{CC}=15V)	I_{SC}	-30	-180	mA
OSCILLATOR SECTION				
Frequency (V_{CC}=15V,Tj=25°C,R_T=10k,C_T=3.3nF) (V_{CC}=15V, T_A=Tlow to Thigh,R_T=10k,C_T=3.3nF)	f_{osc}	47 46	57 60	kHz
Frequency Change with Voltage (V_{CC}=12V to 25V, T_A=Tlow to Thigh,R_T=10k,C_T=3.3nF)	$\Delta f_{osc}/\Delta V$		1.0	%
Discharge Current (Vosc=2.0V, V_{CC}=15V) Tj=25°C T_A=Tlow to Thigh	Idisch	7.5 7.2	9.3 9.5	mA
ERROR AMPLIFIER SECTION				
Voltage Feedback Input (V_O=2.5V,V_{CC}=15V, T_A=Tlow to Thigh)	V_{FB}	2.42	2.58	V
Input Bias Current (V_{FB}=2.7V,V_{CC}=15V, T_A=Tlow to Thigh)	I_{IB}		-2.0	μA
Open Loop Voltage Gain (V_O=2.0V to 4.0V,V_{CC}=15V, T_A=Tlow to Thigh)	A_{VOL}	65		dB
Unity Gain Bandwidth (V_{CC}=15V, T_A=Tlow to Thigh)	BW	0.7		MHz
Power Supply Rejection Ratio (V_{CC}=12V to 25V, Vo=3.0V, T_A=Tlow to Thigh)	PSRR	60		dB
Output Current Sink (V_O=1.1V,V_{FB}=2.7V, V_{CC}=15V, T_A=Tlow to Thigh) Source (V_O=5.0V,V_{FB}=2.3V, V_{CC}=15V, T_A=Tlow to Thigh)	I_{Sink} I_{Source}	2.0 -0.5		mA
Output Voltage Swing High State (V_{FB}=2.3V, V_{CC}=15V,$R_{L(GND)}$=15k, T_A=Tlow to Thigh) Low State (V_{FB}=2.7V, V_{CC}=15V,$R_{L(5.0)}$=15k, T_A=Tlow to Thigh)	V_{OH} V_{OL}	5.0	 1.1	V
CURRENT SENSE SECTION				
Current Sense Input Voltage Gain (V_{FB}=0V, V_{CC}=15V, T_A=Tlow to Thigh)	Av	2.85	3.15	V/V
Maximum Current Sense Input Threshold (V_{FB}=0V, V_{CC}=15V, T_A=Tlow to Thigh)	Vth	0.9	1.1	V
Input Bias Current (V_{CC}=15V, T_A=Tlow to Thigh)	I_{IB}		-10	μA
Propagation Delay (Current Sense Input to Output) (V_{CC}=15V, T_A=Tlow to Thigh)	t_{PLH}		300	ns

ELECTRICAL CHARACTERISTICS (Vcc= 15V unless otherwise noted)

Characteristics	Symbol	Min	Max	Unit
OUTPUT SECTION				

Output Voltage
  Low State (Sink=20mA, V_{CC}=15V)
        (Sink=200mA, V_{CC}=15V)
  High State (Sink=-20mA, V_{CC}=15V)
        (Sink=-200mA, V_{CC}=15V)
	V_{OL}
	
	V_{OH}
		
		13
		12
			
			0.4
			2.2
				V

Output Voltage with UVLO Activated (V_{CC}=6.0V, I_{Sink},=1.0mA, T_A=Tlow to Thigh)	$V_{OL(UVLO)}$		1.1	V
Output Voltage Rise Time (C_L=1.0nF, V_{CC}=15V, T_A=Tlow to Thigh)	tr		150	ns
Output Voltage Fall Time (C_L=1.0nF, V_{CC}=15V, T_A=Tlow to Thigh)	tf		150	ns
ONDERVOLTAGE LOCKOUT SECTION				
Startup Threshold (V_{CC}=0V to 15V,T_A=Tlow to Thigh)	Vth	7.8	9.0	V
Minimum Operating Voltage After Turn-On (V_{CC}=15V to 0V,T_A=Tlow to Thigh)	$V_{CC(min)}$	7.0	8.2	V
PWM SECTION				
Duty Cycle Maximum (V_{CC}=15V, T_A=Tlow to Thigh,R_T=10k,C_T=3.3nF) Minimum (V_{CC}=15V, T_A=Tlow to Thigh,R_T=10k,C_T=3.3nF)	 DCmax DCmin	 94	 0	%
TOTAL DEVICE				

Power Supply Current
        Startup: V_{CC}=6.5V
        V_{CC}=15V Operating
	I_{CC}		1.0
			17
				mA

Power Supply Zener Voltage (I_{CC}=25mA, V_{CC}=0 to 40V)	Vz	30	40	V

NOTES: 1. Vfinal= V_{ref25} $\pm$(Reg_{line}+ Reg_{load})/1000$\pm$ | V_{ref70}(V_{ref0})-V_{ref25} |

V_{ref25}=Vref @ T_A=25°C;
V_{ref70}=Vref @ T_A=70°C;
V_{ref0} =Vref @ T_A=0°C.

2. Tlow= 0°C ; Thigh=+70°C

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N SUFFIX PLASTIC DIP
(MS – 001BA)
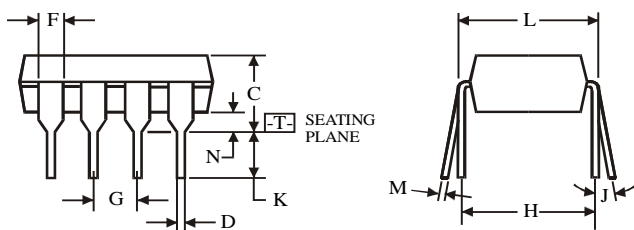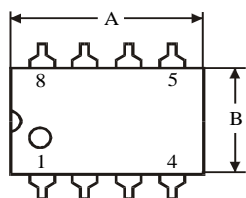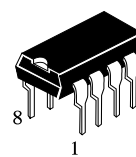
	Dimension, mm	
Symbol	**MIN**	**MAX**
A	8.51	10.16
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

NOTES:

1. Dimensions "A", "B" do not include mold flash or protrusions.

   Maximum mold flash or protrusions 0.25 mm (0.010) per side.

D SUFFIX SOIC
(MS - 012AA)
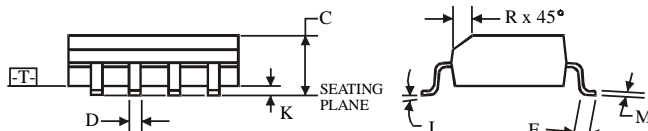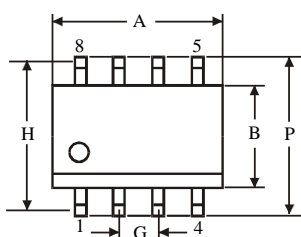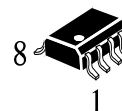
	Dimension, mm	
Symbol	**MIN**	**MAX**
A	4.8	5
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

NOTES:

1. Dimensions A and B do not include mold flash or protrusion.

2. Maximum mold flash or protrusion 0.15 mm (0.006) per side
   for A; for B ‑ 0.25 mm (0.010) per side.

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